

Appl. No. 10/715,611

Date: April 2, 2004
Attorney Docket No. 10113171**AMENDMENTS TO THE SPECIFICATION**

Please replace the paragraph beginning at page 3, line 21 with the following rewritten paragraph:

As described in Figs. 1A and 1B, the channel region between drain region 112 and source region 114 is shortened resulting from the extension of drain region 112 and source region 114. Therefore, exerting a lower voltage between drain region 112 and source region 114 can cause electric conduction, thereby negatively affecting the electric performance of device region 101. ~~The SEM photograph shown in Fig. 3 illustrates a bit line contact structure fabricated by the aforementioned flow. The area A in Fig. 3 illustrates the extended drain region 112 resulting from doping dopant 10 therein.~~

Please delete the paragraph beginning at page 5, line 13 beginning with "Fig. 3 ..."

Please delete the paragraph beginning at page 5, line 15 beginning with "Fig. 4 ..."

Please delete the paragraph beginning at page 8, line 29 beginning with "A SEM photograh ..."